RENESAS

R2A20101BM/NP

Monolithic Synchronous Step-Down DC/DC Converter

REJ03D0790-0300 Rev.3.00 May 14, 2008

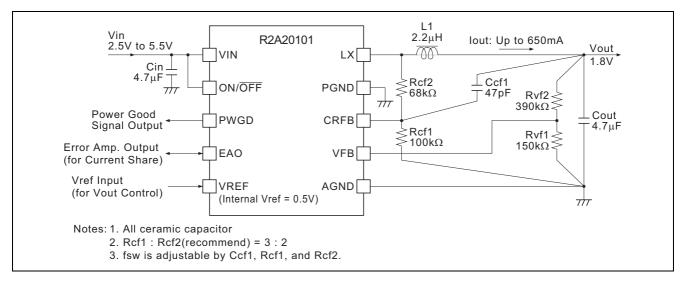
Features

- Built-in low Ron power MOS FETs Pch Ron = 0.30Ω (Typ), Nch Ron = 0.14Ω (Typ)
- High switching frequency: 2 MHz (Max)
- Output current: 650 mA (Max)
- Output ON/OFF control
- Vout control
- Power good monitor
- Current share for redundant power supply operation
- Vout = 0.5 V to (VIN 0.5) V

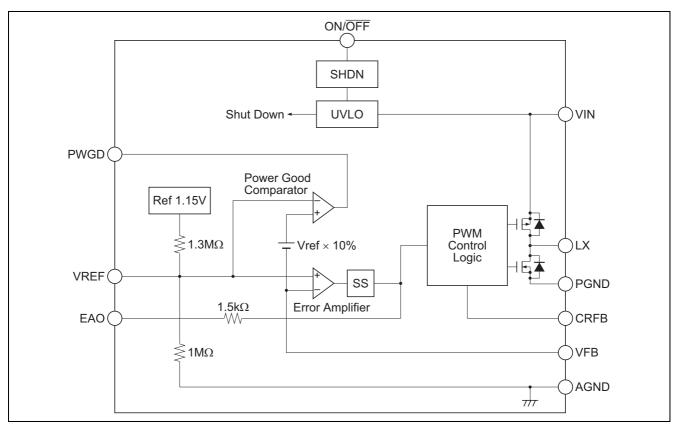
Application

- POL (Point of Load) power supplies
- Power supply for microcomputer systems MCU-Core, I/O, Memory (DDR, SRAM, FLASH, HDD, etc.), FPGA, DSP, Graphic Processor
- Battery powered equipment systems Cellular phone (CDMA power amplifier, MCU, DSP, ASIC), PDA, Digital camera, Portable game, Handy terminal

Operating Circuit Example



Block Diagram



Absolute Maximum Ratings

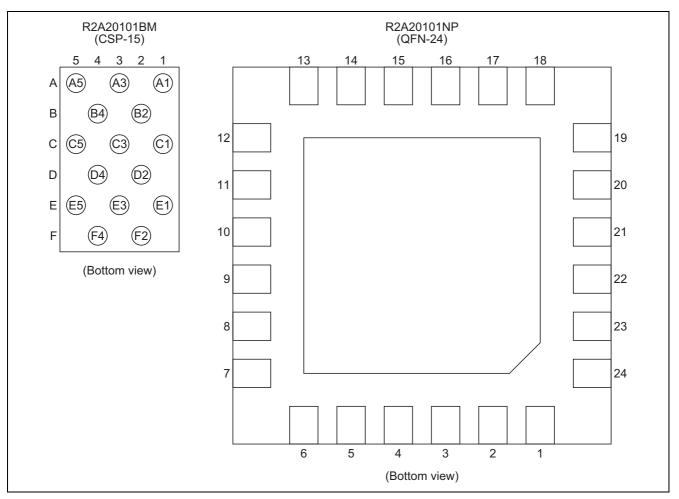
 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit	Note	
Power supply voltage	V _{IN}	6	V	1	
ON/OFF, PWGD, EAO, VREF,	V _{MAX}	-0.3 to (V _{IN} + 0.3)	V	1	
LX, CRFB, VFB terminal voltage					
PGND terminal voltage	V _{PGND}	-0.3 to +0.3	V	1	
Operating ambient temperature	Topr(Ta)	-40 to +85	°C		
Junction temperature 1	Tjmax1	+125	°C		
Junction temperature 2	Tjmax2	+150	°C	2	
Storage temperature	Tstg	-55 to +150	°C		

Notes: 1. Rated voltages are with reference to the AGND pin.

2. Operation by Tjmax2 is made within 24 hours through life.

Pin Arrangement



Pin Description

Pin No.					
R2A20101BM (CSP-15)	R2A20101NP (QFN-24)	Pin Name	Pin Function		
A1, A3, A5	15, 16, 17	PGND	Power ground		
B2, B4	11, 20	LX	Inductor connection node		
C1, C3, C5	10, 21	VIN	Power supply voltage input		
D4	22	ON/OFF	Output on/off control input		
D2	9	CRFB	CR feedback input		
E5	23	PWGD	Power good monitor output		
E1	8	VFB	Feedback voltage input		
F4	2	EAO	Error amplifier output (for current share)		
E3	5	VREF	Vout control voltage input		
F2	4	AGND	Analog ground (IC chip ground voltage)		

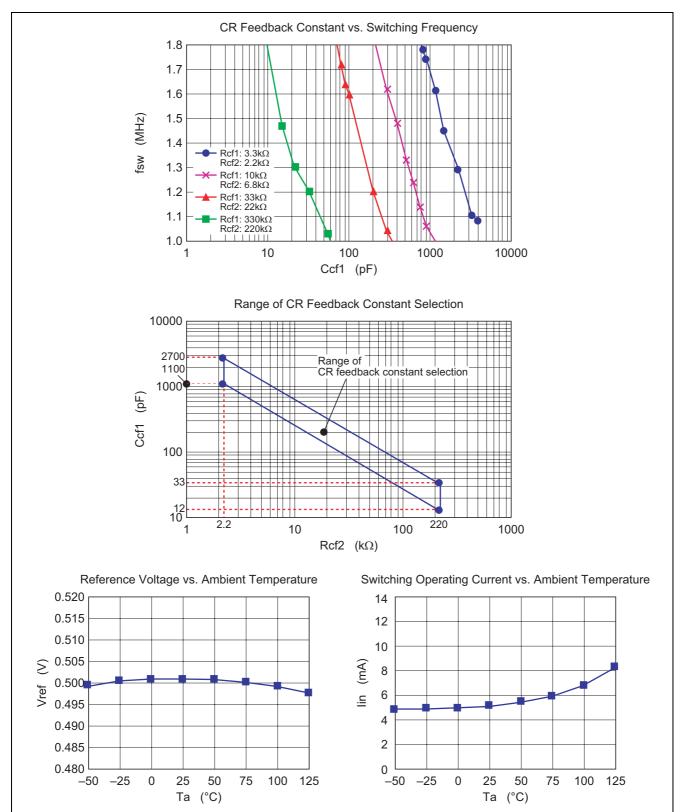
Note: Please apply solder to pins 1, 3, 6, 7, 12, 13, 14, 18, 19, and 24 even though they are NC pins. Solder on the underside pads improves heat-radiation characteristics.

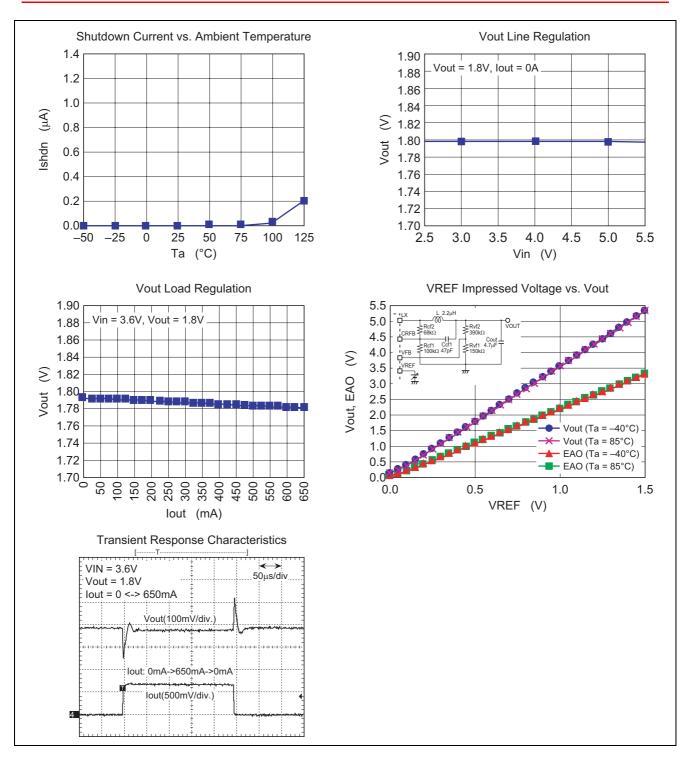
Electrical Characteristics

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Input voltage range	Vin	2.5	—	5.5	V	
UVL threshold high	Vuvl-Hi	2.0	2.3	2.5	V	VFB = CRFB = GND,
						Vin = rising
UVL hysteresis	Vuvl-Hys	0.15	0.22	0.29	V	
Quiescent supply current	lss	20	45	80	μA	
Shutdown supply current	Ishdn		0.0	1.0	μA	$ON/\overline{OFF} = 0V$
Reference voltage	Vref	0.485	0.500	0.515	V	
Vref line regulation	dVref/dVin	(-0.4)	0.1	(0)	%/V	Vin = 2.5 to 5.5V
Vref temperature stability	dVref/dTa	_	(±100)	—	ppm/°C	Ta = -40 to +85°C
VREF sink current	lvref-sink	1.3	3.7	8.0	μA	Vref = 2.5V
VREF source current	Ivref-source	0.3	0.9	2.0	μA	Vref = 0V
VFB leakage current	lleak-VFB	-1	0	+1	μΑ	$VFB = 1/2 \times Vin$
Pch FET on resistance	Ron-Pch	_	0.30	0.50	Ω	VFB = CRFB = 0V,
						ILX = -100mA
Nch FET on resistance	Ron-Nch	—	0.14	0.25	Ω	VFB = CRFB = Vin,
						ILX = 100mA
Pch FET leakage current	lleak-Pch	_	—	1.0	μΑ	$ON/\overline{OFF} = 0V, LX = 0V$
Nch FET leakage current	lleak-Nch	_	—	1.0	μΑ	$ON/\overline{OFF} = 0V, LX = Vin$
Peak current limit	Ipeak-Limit	0.7	—		Α	
ON/OFF threshold high	Von/off-Hi	1.0	1.45	1.85	V	ON/OFF = rising
ON/OFF threshold low	Von/off-Lo	0.75	1.24	1.65	V	ON/OFF = falling
ON/OFF leakage current	lleak-on/off	-1	0	+1	μA	ON/OFF = Vin
ON/OFF input current	linput-on/off		1.4	5	μΑ	$ON/\overline{OFF} = 0.9V$
Switching frequency	fsw	Adjustable by external Ccf1, Rcf1, Rcf2		Hz		
Soft start time	tss	$56 \times \text{Rcf1/(Rcf1 + Rcf2)} \times \text{Vout}$			μS	
Power good threshold	Vth-PGood	(–15)	-10	(–5)	%	Vref = 0.5V
Power good VOL	lpg-VOL	20	_	_	μA	PWGD = 0.2V, VFB = 0V
Power good VOH	lpg-VOH	-10	_	_	μΑ	PWGD = 3.4V, VFB = 0.5V
Output voltage load regulation	dVout/dlout	_	±0.7	—	%/A	L = 2.2µH, Vout = 1.8V,
						lout = 0 to 650mA

Note: () is design spec.

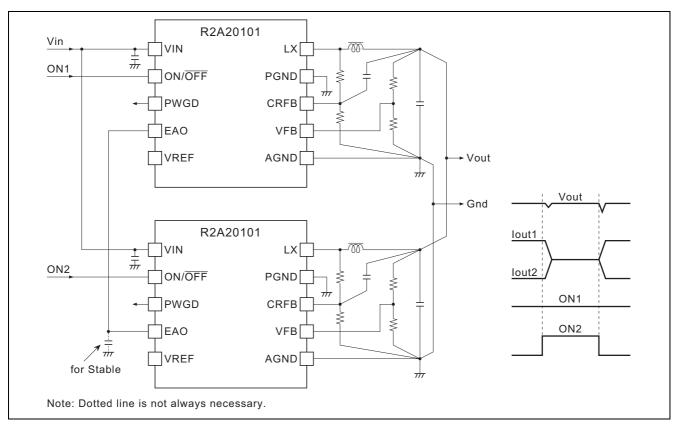
Main Characteristics



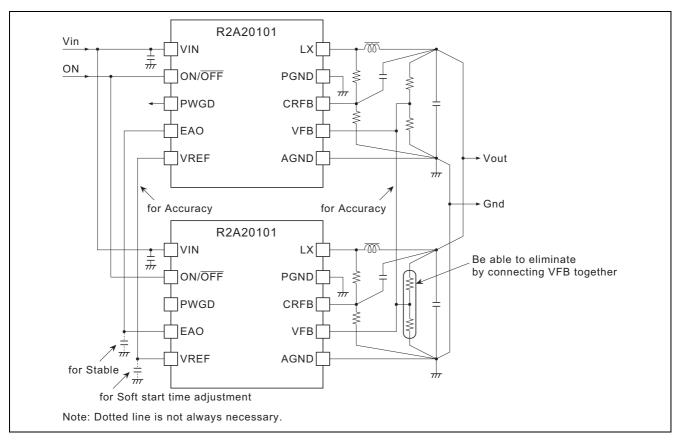


Application Circuit Example

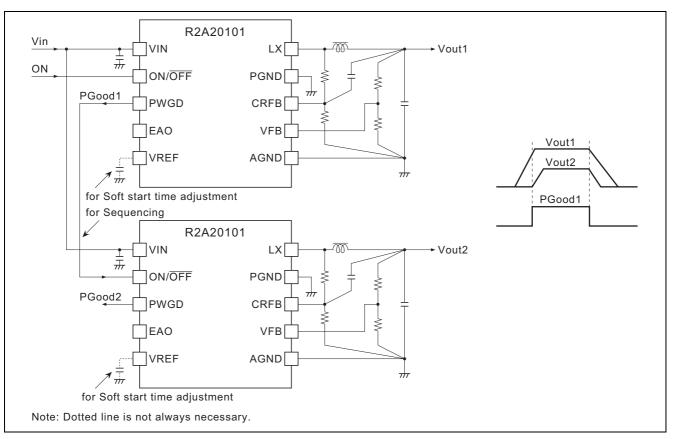
1. Current Share 1 (Redundant, Hot Swap type)



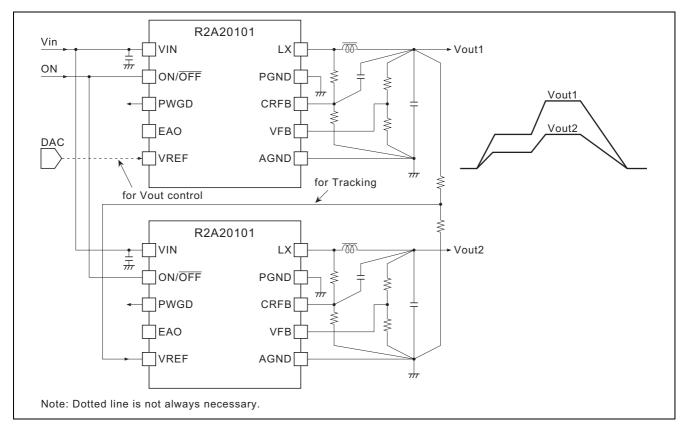
2. Current Share 2 (Accuracy type)



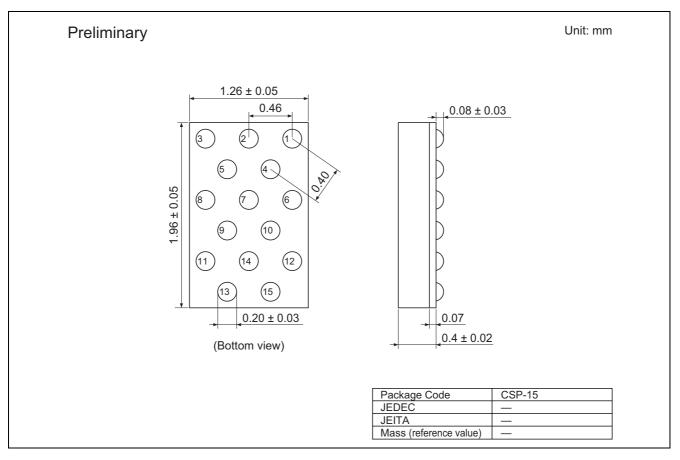
3. Sequential Start-up

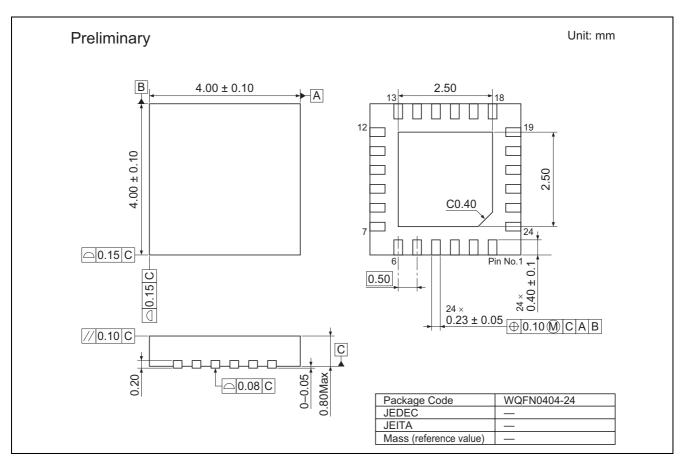


4. Tracking



Package Dimensions





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